

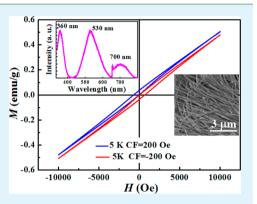
Synthesis, Optical, and Magnetic Properties of Ba₂Ni₃F₁₀ Nanowires

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Supporting Information

ABSTRACT: A low-temperature hydrothermal route has been developed, and pure phase Ba₂Ni₃F₁₀ nanowires have been successfully prepared under optimized conditions. Under the 325 nm excitation, the Ba₂Ni₃F₁₀ nanowires exhibit three emission bands with peak positions locating at 360, 530, and 700 nm, respectively. Combined with the first-principles calculations, the photoluminescence property can be explained by the electron transitions between the t_{2g} and e_g orbitals. Clear hysteresis loops observed below the temperature of 60 K demonstrates the weak ferromagnetism in Ba₂Ni₃F₁₀ nanowires, which has been attributed to the surface strain of nanowires. Exchange bias with blocking temperature of 55 K has been observed, which originates from the magnetization pinning under the cooling field due to antiferromagnetic core/ weak ferromagnetic shell structure of Ba2Ni3F10 nanowires.





1. INTRODUCTION

Fluorides have attracted considerable research interest because of their optical properties, especially the photoluminescence (PL), which has been successfully applied in the phosphorconverted white light-emitting diodes. 1,2 Recently, partial fluorides containing the octahedra have also been considered as potential candidates for the single-phase multiferroic materials with the simultaneous coexistence of magnetism and ferroelectricity.³ Because of the higher electronegativity of F compared with O, the M-F (M denotes metallic ion) bond is more ionic than the M-O one. Thus, weaker hybridization can be expected between M and F, and no significant charge transfer occurs in the M-F bond which is common in oxide ferroelectrics.⁴ This indicates that the ferroelectricity in fluorides is of different origin than in the prototypical perovskite ferroelectrics,⁵ and the d⁰ criterion holding for the oxide perovskites that 3d transition-metal ions must have zero d electrons for ferroelectricity might be avoided.⁶

Among various fluorides, a family of isostructural materials $Ba_2N_3F_{10}$, N = Zn, Co, Ni, have received much interest because of their particular crystal structure and complicated magnetic configurations.^{7,8} The main obstacle for the studies of fluorides is the harsh conditions for preparing pure phase samples. For example, the traditional method for synthesis of Ba₂Ni₃F₁₀ is the solid-state reaction, by melting BaF2 and NiF2 in an HF atmosphere sealed in a noble metal (such as Au, Pt, etc.) tube at high temperatures (generally above 850 °C).

Till now, most works on fluorides are on bulk samples while very rarely fluoride nanostructures were studied. 10,11 In fact, nanostructural materials with reduced dimension are uniquely

important because of their special shape, compositions, and chemical and physical properties, which may shed light on novel optoelectric applications. 12–16 In this work, we develop a novel low-temperature synthesis route based on the hydrothermal method, and pure phase Ba₂Ni₃F₁₀ nanowires (NWs) have been successfully prepared under optimized conditions. Then the optical and magnetic properties of Ba₂Ni₃F₁₀ NWs are studied, which show novel three-color fluorescence and exchange bias.

2. EXPERIMENTAL AND COMPUTATIONAL METHODS

2.1. Sample Growth. Pure phase Ba2Ni3F10 NWs were synthesized by a low-temperature hydrothermal method, based on the experience of the preparation of pure phase $BaAF_4$ (A = Mn, Co, Ni, etc.). ^{17–19} The molar ratio of raw materials BaF₂ and NiF₂ is 1:4. They were dissolved in trifluoroacetic acid solution (2 mL of CF₃COOH and 5 mL of distilled water), and the diluted solution was formed by magnetic stirring, which was then put into a 23 mL autoclave. The autoclave was gradually heated to 200 °C, held for 12 or 24 h, then slowly cooled down to room temperature at a speed of 5-20 °C·h⁻¹. The upper remaining liquid was discarded, and the precipitates were kept and washed with ethanol and distilled water for several times. The washed products were placed in a vacuum drying oven and dried at 60 $^{\circ}\text{C},$ resulting in the final light yellow powders.

2.2. Optical and Magnetic Measurements. The structure of Ba₂Ni₃F₁₀ NWs was studied by X-ray diffraction (XRD) (Rigaku Smartlab3) using Cu K α radiation and a transmission electron

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microscope (TEM, Tecnai F20). The morphology was studied by a scanning electron microscope (SEM, FEI Inspection F50). The PL spectra were recorded using a LabRAM HR800 Raman system with 325 nm He-Cd laser excitation. Absorption measurement was carried out with a spectrophotometer (UV-3600), and the fluorescence efficiency (characterized as the absolute quantum yield) was recorded on an Edinburgh FLS920P spectrometer with an integrating sphere. All the optical measurements were conducted at room temperature and atmospheric pressure. The dc magnetization was measured by a SQUID-VSM (SQUID, Quantum Design) from 5 to 300 K.

2.3. First-Principles Calculations. The first-principles density functional theory (DFT) calculations were based on the projected augmented wave pseudopotentials using the Vienna \overline{ab} initio simulation package. \overline{ab} The GGA+ \overline{U} method is employed using the Dudarev implementation⁴ and various values of the effective Hubbard coefficient $(U_{\text{eff}} = U - J)$ on Ni's 3d states have been tested from 0 to 2 eV. Both the lattice constants and internal atomic positions are fully optimized until the Hellmann-Feynman forces converged to less than 0.01 eV/Å. The experimental antiferromagnetism was adopted.^{7,8} More details of DFT calculation are shown in the Supporting Information.

3. RESULTS AND DISCUSSION

3.1. Fabrication and Morphology of Ba₂Ni₃F₁₀ NWs. In this work, the Ba2Ni3F10 NWs were prepared by the hydrothermal method at 200 °C. We modify only the holding time at 200 °C and the cooling rate, and all other parameters are kept identical. Figure 1a-j shows the morphology of Ba₂Ni₃F₁₀ samples under various synthesis conditions. The information on samples is denoted as Sn(B:C), where n is the sample number, B is the holding time (h) of reactants at a temperature of 200 °C, and C represents the cooling rate (°C· h⁻¹). It can be seen that all samples exhibit broccoli-like shape. A magnified view can recognize the difference between samples

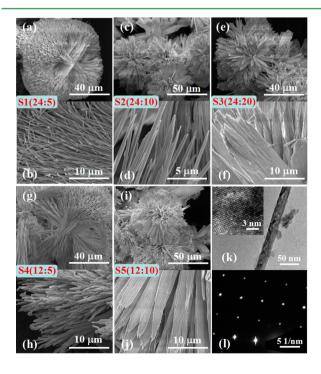


Figure 1. (a-j) SEM images of Ba₂Ni₃F₁₀ synthesized under different conditions shown in brackets (the left number denotes the holding time at 200 °C in h, and the right number denotes the cooling rate in $^{\circ}\text{C}\cdot\text{h}^{-1}$). (k, l) TEM analysis of a single Ba₂Ni₃F₁₀ NW. (k) Morphology at a low magnification with the inset showing the corresponding HRTEM image. (1) The SEAD pattern of a single NW.

prepared under different conditions. For the sample S1 with the longest holding time and slowest cooling rate, well-shaped Ba₂Ni₃F₁₀ NWs (300-500 nm in width and several tenth of μ m in length) make up the broccoli. With increasing the cooling rate to 10 $^{\circ}$ C·h⁻¹ (S2) and 20 $^{\circ}$ C·h⁻¹ (S3), the length of NWs is maintained, but the width becomes larger (700-900 nm for S2), and finally the shape changes to microsheets (width of 7– 10 μ m for S3). With decreasing the holding time to 12 h, though the NWs morphology is main, they look rather nonuniform and the surfaces become quite rough, indicating the possible incomplete growth of the NWs. With further increasing the cooling rate to 10 °C·h⁻¹ (S5), microsheets instead of NWs are formed. On the basis of the above observations, we can conclude that slower cooling rate and longer holding time may facilitate the growth of NWs.

All aforementioned samples were characterized by XRD, which show similar patterns without any impurity phase, as shown in Figure S1 (Supporting Information). The typical XRD pattern from sample S1 is shown in Figure 2a, which matches well with the data of standard PDF no. 26-0172 of Ba₂Ni₃F₁₀. Selected area electron diffraction (SEAD) and highresolution transmission electron microscopy (HRTEM) were measured on individual single nanowire from sample S1, as shown in Figure 1k,l. The regularly arranged spots array reveals the single-crystalline nature of Ba₂Ni₃F₁₀ individual nanowire. Above characterizations clearly demonstrate the easy and successful fabrication of pure phase Ba2Ni3F10. The unit cell of Ba₂Ni₃F₁₀ is monoclinic with space group C2/m, built up from infinite rutile chains connected together by chains of corner-sharing octahedra and bioctahedral units, as shown in Figure 2b,c. Ni atoms are distributed among three sublattices and form odd cycles. ^{7,8} Since sample S1(24:5) exhibits the best nanowire morphologies with pure phase crystalline structure, the following optical and magnetic measurements are mainly performed on this sample.

3.2. Optical Properties and First-Principles Calculations. As shown in Figure 3a, PL spectrum from a bundle of Ba₂Ni₃F₁₀ NWs was measured in a range from 340 to 800 nm under the excitation of 325 nm laser. Three emission peaks are observed and locate respectively at 360, 530, and 700 nm, which occupy the ultraviolet, green, and red regions. Such fluorescence is a very promising option for applications in various fields of science and technology. 23-25 There is a sudden jump at around 650 nm, which is an artifact due to frequency multiplication effect of the equipment. To avoid the influence of this artifact, the whole absolute quantum yield (η) under the excitation of 325 nm was measured and divided into two parts, η is 48% in the range of 340~640 nm, while in the range from 670 to 750 nm, it is as high as 87%. The peak of 700 nm is much broader than the former two, which suggests that its emission mechanism is probably from defects or vacancies.²⁶ Ultraviolet visible (UV-vis) absorption spectrum of Ba₂Ni₃F₁₀ NWs is shown in Figure 3b. Because of the equipment limitation, the lowest wavelength can only be measured down to 190 nm. Two sharp absorption peaks located at 200 and 430 nm, and a broad peak above 550 nm, are observed. Obvious absorption edges are seen in P_1 and P_2 , which can be fitted according to eq 1,

$$\alpha(E) = \frac{A}{E} (E - E_{g,dir})^{1/2} + \frac{B}{E} (E - E_{g,ind} \mp E_{ph})^2$$
 (1)

where $\alpha(E)$ is the absorption coefficient, $E_{\rm g,dir}$ is the direct gap energy, $E_{g,ind}$ is the indirect gap enery, E_{ph} is the phonon energy

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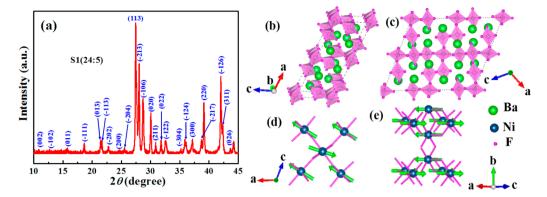


Figure 2. (a) XRD pattern of $Ba_2Ni_3F_{10}$ NWs of S1 synthesized using the hydrothermal method. XRD for other samples can be found in the Supporting Information. (b,c) The schematic crystal structure of $Ba_2Ni_3F_{10}$ unit cell. Ba and F atoms are large green and small red spheres, respectively. NiF₆ octahedra are plotted in light pink. (d,e) The magnetic structure of $Ba_2Ni_3F_{10}$ shown in the ac plane and along the b direction, respectively.

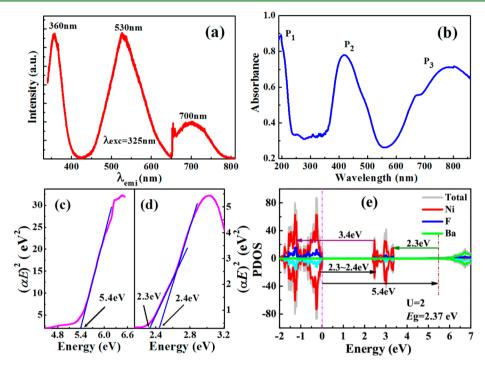


Figure 3. (a) PL spectrum of $Ba_2Ni_3F_{10}$ NWs excited by 325 nm laser. (b) Absorption spectrum. (c,d) The analysis of band gap from the absorption spectrum. (e) PDOS of $Ba_2Ni_3F_{10}$.

mediating any indirect gap component, E is the photon energy, and E and E are constants. This approach is developed for traditional semiconductors with single parabolic bands and has been extended to analyze other compounds. Figure 3c,d shows the linear fitting of $(\alpha E)^2$ vs energy, indicating the direct band gap in $Ba_2Ni_3F_{10}$ NWs. Furthermore, there are three linear regions, which are all applied by the linear fitting. The band gaps obtained by the fitting are 5.4 eV (from the edge of P_1), 2.3 eV, and 2.4 eV (from the edge of P_2).

To figure out the underlying mechanism of such novel emission, we further carried out first-principles calculations. By variation of the Hubbard coefficient, it was found that $U_{\rm eff}=2$ eV gives the best description for the ${\rm Ba_2Ni_3F_{10}}$. The density of state (DOS) and projected density of states (PDOS) show that the electronic bands near the Fermi level are from the Ni 3d orbitals, as shown in Figure 3e. Because of the distorted cornerand edge-sharing Ni–F₆ octahedra, a weak hybridization between Ni's 3d orbitals and F's 2p orbitals is presented. The

local magnetic moment within the Wigner-Seitz sphere was 1.73 $\mu_{\rm B}$ per Ni atom, implying the high-spin state for Ni²⁺ ($t_{\rm 2g}^{\ 6}e_{\rm g}^{\ 2}$), as expected. Namely, the $t_{\rm 2g}$ orbitals are fully occupied and $e_{\rm g}$ orbitals are half-filled.

The band gap of $\mathrm{Ba_2Ni_3F_{10}}$ in our DFT calculation was about 2.37 eV (when $U_{\mathrm{eff}}=2$ eV), separating the empty upper-Hubbard $\mathrm{e_g}$ bands and occupied lower-Hubbard $\mathrm{e_g}$ bands. This Mott gap coincides with the emission phonon energy. According to Figure 3d, the emission and the self-absorption can be well mapped to the transitions among these sub-bands. First, the electrons are excited to the unoccupied upper-Hubbard $\mathrm{e_g}$ orbitals of Ni ions and unoccupied d orbitals of Ba ions by the 325 nm laser, leading to the absorption spectra in Figure 3b, then the excited electrons jump from such unoccupied orbitals to the occupied $\mathrm{e_g}$ and $\mathrm{t_{2g}}$ orbitals of Ni ions, leading to the PL emissions at 360 and 530 nm (see Figure 3a).

It is rare for a fluorescent material to emit three-color light simultaneously and efficiently. Our discovery of $\mathrm{Ba_2Ni_3F_{10}}$ as a fluorescent material with interesting three-color emissions will shed light on potential applications of optoelectrics. The only drawback is that one color is in the ultraviolet range. In future, the peak position of ultraviolet emission may be shifted to the violet or blue region by the proper ion substitution or structure modification; thus, it can be applied in the phosphor-converted white light-emitting diodes.

3.3. Exchange Bias Effect and Possible Multiferroic Material. Apart from the synthesis and optical properties, magnetic characterization of $Ba_2Ni_3F_{10}$ NWs was also performed. The temperature-dependent magnetization (M-T) curves were measured under a magnetic field of 200 Oe after zero field cooling (ZFC) and field cooling (FC) processes with a cooling field (H_{cool}) of 200 Oe. As shown in Figure 4, a

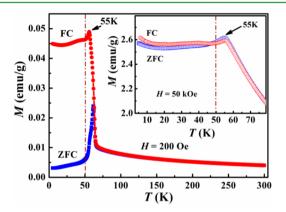


Figure 4. ZFC and FC M-T curves of Ba₂Ni₃F₁₀ NWs measured under H = 200 Oe. ZFC and FC M-T curves measured under H = 50 kOe (inset).

splitting of ZFC and FC M-T curves is observed below 60 K. Maxima can be observed in both curves, below which magnetization decreases with further decreasing temperature, indicating the antiferromagnetic (AFM) nature. We define the Néel temperature (T_N) of 55 K from the maximum of FC M-Tcurve, which is close to the reported $T_{\rm N}$ of 50 K for a singlecrystal sample. The ZFC and FC M-T curves were further measured under a magnetic field of 50 kOe with $H_{\rm cool}$ of 50 kOe for FC process. Clear maximum can still be observed at 55 K, which confirms the AFM transition, and excludes the possible spin glass behavior.³² Interestingly, the ZFC moment is higher than the FC one in the temperature range close to $T_{\rm N}$. This abnormal phenomenon might be related to the frustrated spin structure. Competition between strong AFM and weak ferromagnetic (FM) interactions within even cycles of cornersharing and edge-sharing octahedra leads to a frustrated AFM coupling in bioctahedra units while nonfrustrated rutile-like chains exhibit a normal FM coupling.8 Under the high cooling field, the frustrated spin structure is broken, and there might be some metastable states for the alignment of the spins during the cooling process due to the magnetocrystalline anisotropy. During the warming process, the high field tends to align all the spins to the field direction in both FC and ZFC cases by the Zeeman energy, and slight difference can be observed between the FC and ZFC magnetization with slightly larger FC magnetization due to the prealignment of spins during the FC cooling process. However, in the temperature range close to $T_{\rm N}$, thermal activation is comparable to the AFM interaction.

Thus, the spins are easier to be aligned by the measuring field in the ZFC case, while in the FC case, the spins are harder to be aligned by the measuring field because of the magnetocrystal-line anisotropy, leading to smaller magnetization in the FC case compared to that of the ZFC one.

Figure 5a shows the field-dependent magnetization (M-H)loops of Ba2Ni3F10 NWs measured at 5 K after cooling from 300 K with H_{cool} of 200 Oe. Clear hysteretic M-H loop has been observed, revealing the weak FM behavior. 33-35 It has been reported that nonfrustrated rutile-like chains exhibit a normal FM coupling, although previous reports achieved only linear M-H curves of Ba₂Ni₃F₁₀ single crystal at any temperature in the range of $4.2 \sim 300$ K.^{7,8} The measuring artifact can be excluded since we also measured the M-H curve at 300 K, and nonhysteretic linear M-H curve is observed and shown in the left inset of Figure 5a. We further measured the M-H curve at 20 and 65 K, which is just below and above T_N . The clear hysteresis loop at 20 K and linear curve at 65 K, as shown in Figure S2 (Supporting Information), further confirm the weak ferromagnetism. Recently, Borisov et al. prepared BaCoF₄ film epitaxially, and weak ferromagnetism has been observed in contrast to the AFM nature of bulk sample, which has been ascribed to anisotropic epitaxial strain.³⁶ In our case, due to the nanowire shape of our sample with width of 300-500 nm, it is reasonable to assume the core-shell structure, which is commonly adopted to explain the abnormal magnetic phenomena in magnetic nanostructures.^{37,38} The core of the nanowire has the perfect crystalline structure, which exhibits frustrated antiferromagnetism with linear M-H curve. However, at the shell of the nanowire, large strain might exist and the balance between the AFM and FM interactions is broken, and weak ferromagnetism might be realized.³⁹ Such kind of weak ferromagnetism usually occurs on antiferromagnetic nanostructures. 40,41

By careful investigation of the M-H loop at 5 K with $H_{\rm cool}$ = 200 Oe, a clear shift toward the negative field direction has been observed, which is a clear indication of exchange bias (EB). To exclude the possible artifact due to the measuring system, we change the $H_{\rm cool}$ to -200 Oe, and now the M-H loop at 5 K shifts to the positive field direction. Furthermore, the M-H curve at 300 K passes the original point and shows no shift, which further confirms the validity of observed EB.

Figure 5b shows the temperature dependence of exchange bias field (H_E) and coercive field (H_C) . H_E and H_C are defined as $H_E = -(H_L + H_R)/2$ and $H_C = (H_R - H_L)/2$, where H_L and $H_{\rm R}$ are the left and right coercive fields, respectively. As the temperature increased, H_E gradually decreases to zero at 55 K, which is consistent with the AFM transition temperature. The H_C vs T plot presents a peak value at 55 K with H_C as high as 400 Oe, and then $H_{\rm C}$ decreases drastically with further increasing temperature. This is typical behavior of the AFM/ FM bilayers, ⁴³ confirming the two-layer structure of Ba₂Ni₃F₁₀ NWs with AFM core and weak FM shell. Because of the interfacial exchange coupling, $H_{\rm C}$ shows maximum and does not reach zero at the blocking temperature of $H_{\rm E}$ at 55 K but slightly higher temperature. 43 Besides the shift of M-H curve to the opposite field direction, a perpendicular shift along the magnetization axis can also be observed.³⁷ We further measured the temperature dependence of the shift of M-H loops along the magnetization axis. Here vertical magnetization shift (M_{shift}) and remanent magnetization difference (M_{rem}) are defined as $M_{\text{shift}} = (M_{\text{r}}^+ + M_{\text{r}}^-)/2$ and $M_{\text{rem}} = (M_{\text{r}}^+ - M_{\text{r}}^-)/2$, where M_{r}^+ and M_r^- are the positive and negative remanent magnetization,

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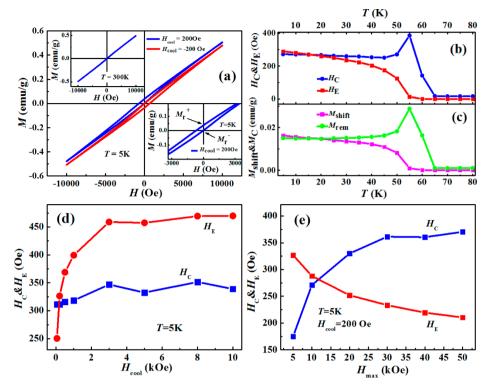


Figure 5. (a) M-H loops at T=5 K after cooling with H_{cool} of 200 and -200 Oe. Left inset: M-H loop measured at T=300 K. Right inset: enlarged view of M-H loop of the aforementioned H_{cool} of 200 Oe. (b) T-dependence of H_E and H_C . (c) T-dependence of M_{shift} and M_{rem} . (d) Dependence of $H_{\rm E}$ and $H_{\rm C}$ on $H_{\rm cool}$ measured at T=5 K with maximum field of 10 kOe. (e) Dependence of $H_{\rm E}$ and $H_{\rm C}$ on $H_{\rm max}$ measured at T=5K with $H_{\text{cool}} = 200$ Oe.

respectively, indicated in the right inset of Figure 5a. The vertical shift of loop is quite commonly observed in the exchange bias of those nanomagnetic systems.³⁷ Physically, this vertical shift might be due to the uncompensated spins at the interface/surface, which contribute to a significant portion of total magnetization in these systems. Then the pinning of these moments leads to vertical shift in the M-H loops.⁴³ As shown in Figure 5c, the $M_{\rm shift}$ and $M_{\rm rem}$ show similar temperature dependence as $H_{\rm E}$ and $H_{\rm C}$, respectively.

The influence of H_{cool} on H_{E} and H_{C} was further studied, and the results are shown in Figure 5d. $H_{\rm E}$ increases abruptly with increasing H_{cool} to about 3 kOe and then saturates with further increasing H_{cool} , while H_{C} only increases slightly and then saturates with $H_{\rm cool}$ above 3 kOe. This is significantly distinct from those systems with spin glass layer in which the $H_{\rm E}$ decreases with increasing $H_{\rm cool}$ and consistent with the typical AFM/FM bilayer system in which $H_{\rm E}$ increases with increasing cooling field and saturates at high cooling field.45 This further confirms the core-shell structure of AFM core and weak FM shell in Ba₂Ni₃F₁₀ NWs. To explore the relationship between maximum applied magnetic field (H_{max}) and EB, we measured the M-H loops with various H_{max} after cooling under a field of 200 Oe. As seen in Figure 5e and at T = 5 K, $H_{\rm E}$ decreases and $H_{\rm C}$ increases quickly with increasing $H_{\rm max}$ to 30 kOe, and then both gradually become saturated. This can be understood by the fact that the large maximum field may induce the partial spin flop at the interface between the AFM core and weak FM shell due to the frustrated spin structure of Ba₂Ni₃F₁₀.46

Although Ba₂Ni₃F₁₀ is not a multiferroic material since its crystal structure is centrosymmetric and no spontaneous polarization is allowed, it is a magnetoelectric material with linear magnetoelectric effect.³⁵ In bulk Ba₂Ni₃F₁₀, the polarization can be induced under the application of a magnetic field, which has been predicted by Nener and Palstra. 47 By preparation of Ba₂Ni₃F₁₀ in NWs, weak ferromagnetism has been realized. Spontaneous polarization might be introduced along the three crystallographic directions by the internal magnetic field due to the weak ferromagnetism even without external magnetic field through the linear magnetoelectric coupling. Thus, Ba₂Ni₃F₁₀ NWs might be a possible multiferroic material with the coexistence of weak ferromagnetism and ferroelectricity, which needs further studies to confirm. Together with the outstanding optical properties, Ba₂Ni₃F₁₀ NWs may become a novel multiferroic material with the simultaneous coexistence and mutual manipulation of optical, magnetic, and ferroelectric properties.

As the single-phase multiferroic materials are very rare due to the contradictory requirements of the outer shell electronic structure, 48 our results might shed light on the realization of novel multiferroic materials. By selecting appropriate magnetoelectric materials, weak ferromagnetism might be induced by the proper strain control. Thus, spontaneous polarization might be induced through the magnetoelectric effect, leading to the coexistence of ferromagnetism and ferroelectricity.

4. CONCLUSIONS

Using hydrothermal technique and under optimized conditions, we have successfully prepared pure phase Ba₂Ni₃F₁₀ NWs. The longer holding time at 200 °C helps the growth of NWs and slower cooling rate narrows the NWs. Under the 325 nm excitation, three color emissions are observed with peaks locating in the regions of ultraviolet (360 nm), green (530 nm), and red (700 nm). The ultraviolet and green bands are interpreted to be the electron transitions between the t_{2g} and e_g levels, which is verified by absorption spectra and first-principles calculations, while the broad red emission is suggested to be from defects.

In contrast to the linear M-H curve in single-crystalline sample, clear hysteresis loop has been observed below the $T_{\rm N}$, which has been attributed to the induced internal strain at the surface of NWs. EB effect is observed at the temperature below 55 K, and has been explained by the exchange coupling between the AFM core and weak FM shell.

ASSOCIATED CONTENT

S Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acsami.6b08110.

Structural characterization for samples and magnetic data for pure $Ba_2Ni_3F_{10}$ NWs; Figure S1 shows the XRD patterns of the aforementioned five samples synthesized by various conditions; Figure S2 sketches the M-H curves measured at T=20 and 65 K after cooling with $H_{\rm cool}$ of 200 Oe; computational method is described in detail (PDF)

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Author Contributions

Q.X. conceived and designed the research. S.Z. carried out the experiment. Y.W. and S.D. developed the theoretical explanation. J.W. and J.D. carried out the magnetic measurements. Z.N. and Z.W. contributed to the optical measurements. S.Z., Q.X., and S.D. wrote the paper.

Notes

The authors declare no competing financial interest.

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